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Article

Role of Fluxes in Optimizing the Optical Properties of $Sr_{0.95}Si_2O_2N_2$:0.05Eu²⁺ Green-Emitting Phosphor

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Abstract: Chlorides of NH₄Cl and SrCl₂ and fluorides of AlF₃ and SrF₂ were added to raw materials acting as the flux for preparing the SrSi₂O₂N₂:Eu²⁺ phosphor. The effects of the fluxes on the phase formation, particle morphology, particle size, and photoluminescence properties were investigated. The results revealed that particle size, particle morphology and photoluminescence intensity were largely dominated by the type of the flux material and its adding amount. The chloride-based flux was found to favor the formation of the SrSi₂O₂N₂:Eu²⁺ phase. Among the chloride-based fluxes, the sample added with the SrCl₂ flux presented the narrow particle distribution and cleaner surface, with enhanced emission intensity and an increased external quantum efficiency by 68% and 22%, respectively, compared with those of the sample without any flux adding.

Keywords: photoluminescence properties; oxynitride phosphor; flux; green emitting

1. Introduction

Recently, phosphor converted white light-emitting diodes (LEDs) have attracted much attention due to their excellent properties of high efficiency, long lifetime, low power consumption and environment-friendly characteristic, compared with those of conventional incandescent and fluorescent lamps [1–10]. Normally, there are two methods to generate white light for phosphor-converted white LEDs. The first method is combination of the blue LED chip with yellow phosphor; the second method is combination of the UV LED chip with blue, green, and red phosphors [3]. As the phosphor is one of the important parts in white LEDs, the photoluminescence properties of the phosphor can determine the performance of the LED device. In order to successfully apply the phosphor-combined LED to the lighting, the used phosphor must work under long-wavelength UV or blue LED chips and have high emission efficiency. There are some factors to affect the optical properties of the phosphor, such as particle size, crystallinity, particle morphology, and composition homogeneity. In addition, defects in the crystal grain are also a main factor to affect the luminescence of phosphor. To overcome the drawbacks mentioned above, adding flux in raw material in the solid-state reaction among various synthetic processes have been used [11-16]. For the flux used, a flux material has a melting point below the solid-state reaction temperature, which can dissolve one or more reaction components and allow the materials to enter the reaction zone. Therefore, the flux addition has great influence on the ion diffusions in the solid-state reaction and particle size distribution, growth condition, crystallization process of the synthesized phosphor as well as the formation of target product matrix with good crystallinity. Besides, by using the flux material, one of the big advantages to be taken is known to reduce the processing temperature, leading to lower the production cost. Previous literature [17–19] has reported that fluxes adding into various phosphors could improve the morphological and optical properties of the phosphor powders. Although flux materials, in general, can optimize the optical properties of the phosphors, the selection of an appropriate flux material and understanding of flux effect on the optical properties may differ from one phosphor to another.

In this work, $Sr_{1-x}Si_2O_2N_2:xEu^{2+}$ phosphor is taken as a sample to understand the role of flux. This phosphor is a new class of green-emitting phosphors used into the white light-emitting diodes (WLEDs), which have superior properties over sulfide and oxide phosphors. The purpose of this work is to add various fluxes (NH₄Cl, SrCl₂, AlF₃, SrF₂) into the raw materials to investigate the effect of flux on the photoluminescence properties and crystal formation of the sample so that an appropriate flux for synthesizing $Sr_{1-x}Si_2O_2N_2:xEu^{2+}$ would be selected. We concentrate on controlling the particle size, particle morphology, and photoluminescence intensity by combining a firing temperature with an appropriate flux, which is an important factor from the applicability of view point.

2. Results and Discussion

Figure 1 gives the XRD patterns of $SrSi_2O_2N_2$:Eu²⁺ with 1 wt % adding amount of different fluxes (NH₄Cl, SrCl₂, SrF₂ and AlF₃) firing at various temperatures. It can be seen from Figure 1a that when the sample doped with NH₄Cl flux was sintered below 1550 °C, the resultant powder was composed of a main phase of SrSi₂O₂N₂ (JCPD card No. 49–0839) and a few SrSiO₃ (JCPD No. 36–0018) impurity phase. Further increased the sintering temperature to 1550 °C, the XRD diffraction peaks matched well

with those in $SrSi_2O_2N_2$ structure with JCPD card No. 49–0840. This indicated that the starting phosphor materials were prone to the low temperature type of $SrSi_2O_2N_2$ when the sintered temperature was below 1550 °C, whereas the high temperature type of $SrSi_2O_2N_2$ was attained at a sintered temperature of above 1550 °C. This result is consistent with that reported in the literature [20]. This lower phase transformation temperature may be due to that NH₄Cl has a decomposition reaction at a much lower temperature than that for the sample synthesis and could be flushed out of the system by the gas flow. As a result, the effect of NH₄Cl as the flux in this reaction may play a role in cleaning effect for the surfaces of the starting particles to improve the reaction reactivity and therefore lower the synthesis temperature of the samples. For the starting materials doped with AlF₃, SrCl₂, SrF₂ fluxes and without any flux, the high temperature phase of $SrSi_2O_2N_2$ was obtained at adding the fluxes into the raw materials can reduce the phase transformation temperature of $SrSi_2O_2N_2$. Moreover, there is not any appreciable flux diffraction peaks could be found in the XRD patterns, indicating that ignorable effect of the flux addition on unpurifying the resultant phosphors.





Figure 2 presents the sintering temperature dependent emission intensity of the phosphors synthesized above. Note that, with the increase of the sintering temperature, the emission intensities of all the samples increased firstly, and then fell down after the emission intensity reached the maximum value. The optimal synthesis temperatures of these samples were mainly dependent on the flux types. For the phosphors with added NH₄Cl, AlF₃, SrCl₂, and SrF₂ fluxes, the optimal sintering temperatures were 1550, 1400, 1500, and 1500 °C, respectively, which are corresponding to the lowest phase transformation temperatures of SrSi₂O₂N₂, as shown in the XRD patterns (Figure 1), indicating that the emission intensity of phosphor composed of SrSi₂O₂N₂ high temperature phase was much higher than that of the sample with SrSi₂O₂N₂ low temperature phase. Thus it can be seen that adding flux can reduce the optimal sintered temperature and enhance the crystallinity effectively, since fluxes melt at lower temperature than the solid-state reaction temperature and act as solvents for the reactants facilitating solid-state reaction, finally resulting in the enhanced emission intensity at a lower sintering temperature.

Figure 2. Emission intensities of the $SrSi_2O_2N_2$:Eu²⁺ sintered at various temperatures with 1% flux.



To further investigate the effects of flux on the phase formation and photoluminescence properties of $SrSi_2O_2N_2$, we have synthesized $SrSi_2O_2N_2$ samples with various adding amounts of different fluxes. The XRD patterns of $SrSi_2O_2N_2$ doped with various amounts of the fluxes are shown in Figure 3. It can be seen that, for the sample doped with NH₄Cl flux, when the NH₄Cl adding amount was increased to 5%, $SrSiO_3$ impurity phase was observed in the resultant sample. The presence of the impurity phase was also observed in the samples doped with certain adding amounts of SrF_2 and AlF_3 fluxes. However, for the samples doped with various adding amounts of $SrCl_2$ flux, all the resultant powders were composed of a single high temperature phase of $SrSi_2O_2N_2$. Therefore, it can be concluded that appropriate flux adding amount is very important for obtaining the $SrSi_2O_2N_2$ with single high temperature phase.



Figure 3. XRD patterns of $SrSi_2O_2N_2:Eu^{2+}$ adding various amounts flux (**a**) NH₄Cl (1550 °C); (**b**) $SrCl_2$ (1500 °C); (**c**) SrF_2 (1500 °C); (**d**) AlF_3 (1400 °C).

Figure 4 gives the effect of the addition amount of various types of fluxes on the emission intensity of $SrSi_2O_2N_2:Eu^{2+}$ phosphor. Note that, the emission intensity enhanced with the increase of the flux adding amount, the strongest emission intensities were obtained for the samples added with 2 wt %, 5 wt %, 3 wt % and 1 wt % of NH₄Cl, SrCl₂, SrF₂ and AlF₃ fluxes. Then the emission intensity was decreased as the adding amounts were further increased. Furthermore, it can be seen from Figure 3 that the strongest emission intensity was achieved for the samples composed of $SrSi_2O_2N_2:Eu^{2+}$ high temperature phase, which indicates that $SrSi_2O_2N_2:Eu^{2+}$ high temperature phase is advantage to obtain stronger photoluminescence properties. From Figure 4, it is known that the proper flux adding amount used in synthesizing sample can obtain optimal emission intensity of the phosphor. This may be due to that the added flux at proper flux adding amount is favorable for controlling the particle size distribution, particle morphology and the crystallinity of the resultant powders.

Figure 4. Effects of flux adding amounts on the emission intensity of $SrSi_2O_2N_2:Eu^{2+}$ phosphor with various kinds of flux.



To compare the photoluminescence properties of the $SrSi_2O_2N_2$:Eu²⁺ phosphors added with and without the flux, the photoluminescence spectra have been determined, as shown in Figure 5. The emission intensity of the sample after adding the flux was stronger than that of the powder without any flux. The reason for increasing emission intensity by adding flux should be ascribed to the crystallinity improvement of the synthesized particles, which would reduce the defects in the lattice and on the surface of the phosphor; simultaneously, and the growth enhancement of the particle size and reduction of the size distribution, which would decrease the light scattering caused by the small particles. The particle size of the synthesized sample without any flux was about 3 µm, whereas the particle sizes of the samples added with NH₄Cl, SrCl₂, SrF₂ and AlF₃ were 5.2, 4.9, 3.49 and 4.18 µm, respectively (see Figure 6). Additionally, another reason responsible for the increased emission is the control of the particle morphology by adding the flux. As seen Figure 7, the sample without adding any flux had small particle size and the particle was not crystallized very well; in contrast, the sample with adding flux had uniform particle morphology, which is advantage to obtain excellent photoluminescence properties. For the samples using various fluxes, the sample added with SrCl₂ had the strongest emission intensity. Compared with the samples added without any flux and with the fluxes of NH₄Cl, AlF₃ and SrF₂, the emission intensity of the SrSi₂O₂N₂:Eu²⁺ with SrCl₂ addition was enhanced evidently. This may be ascribed to every given host material having its proper flux material, which enhances the crystallinity and particle morphology of the resultant powder, finally resulting in improved photoluminescence properties. In our work, the emission intensity was much higher for the sample added with the chlorid fluxes than the sample added with the fluorid fluxes. This may be due to that the melting point of the chlorid flux was much lower than that of the fluorid flux, making the chloride liquid form easily before the formation of the low temperature phase of the $SrSi_2O_2N_2$:Eu²⁺, which would enhance the distribution of the Eu^{2+} ions in the crystal structure. Furthermore, the existence of the liquid phase could increase the contact of the raw material particles and enhance the diffusions of the materials, consequently improving the reaction activity of the powders. For the sample with adding SrCl₂ flux has the strongest emission intensity, which may be considered that the Sr^{2+} ions can compensate the losing Sr^{2+} , which was caused by the volatilization of the released Sr from the SrO decomposition during the reaction.

Figure 5. Effects of various kinds of flux on the emission intensity of $SrSi_2O_2N_2$:Eu²⁺ phosphors.



Figure 6. Particle size distribution of $SrSi_2O_2N_2$:Eu²⁺ with various kinds of flux (**a**) none (1550 °C); (**b**) NH₄Cl (1550 °C, 2%); (**c**) $SrCl_2$ (1500 °C, 5%); (**d**) SrF_2 (1500 °C, 3%); (**e**) AlF₃ (1400 °C, 1%).





Figure 8 gives the external quantum efficiencies of the $SrSi_2O_2N_2:Eu^{2+}$ doped with and without fluxes. Because of the apparatus calibration and stability of determined oxynitride powder in ambient, the degree of confidence on efficiency data can be considered to be qualified. It can be seen that the quantum efficiencies of all the samples doped with flux were stronger than that of the sample without any flux. The external quantum efficiencies of the samples doped with NH₄Cl, SrCl₂, SrF₂ and AlF₃ were 45%, 60%, 42% and 39%, respectively, under 410 nm excitation. Whereas, the external quantum efficiencies may be due to that the crystallinity of the powders was enhanced by adding the flux, resulting in the reduction of the defects in the host lattice and on the surface of the particles. As a result, the possibility of the non-radiation transition within and among the particles was reduced.

Figure 8. Effects of various kinds of flux on the external quantum efficiencies of $SrSi_2O_2N_2$:Eu²⁺ phosphors.



3. Experimental Procedures

A series of the $Sr_{1-x}Si_2O_2N_2:xEu^{2+}$ ($Eu^{2+} = 5 \text{ mol }\%$) samples added with the fluxes of 0.5%–5% of NH₄Cl, SrF₂, AlF₃ and 0.5%–7% of SrCl₂ were synthesized by the solid-state reaction technique at high temperature. Stoichiometric mixtures of SrCO₃ (Kojundo Chemical Laboratory Co. Ltd., Tokyo, Japan), SiO₂ (Kojundo Chemical Laboratory Co. Ltd., Japan), Eu₂O₃ (Shin-Etsu Chemical Co. Ltd., Tokyo, Japan), Si₃N₄ (SN-E10, Ube Industries, Tokyo, Japan), NH₄Cl (Sigma-Aldrich K.K., Tokyo, Japan), SrCl₂ (Wako pure chemical industries Ltd., Louis, USA), SrF₂ (Sigma-Aldrich K.K., Tokyo, Japan), and AlF₃ (Kojundo Chemical Laboratory Co. Ltd., Tokyo, Japan) were weighed out and grounded. The mixed powders were then fired in N₂/5% H₂ between 1400 °C and 1600 °C for 6 h in a tube furnace. After the firing, the power was shut off and the sample was cooled down with the furnace.

The phase purity was determined by X-ray powder diffraction (XRD) (Rigaku, RINT Ultima-III) with Cu-K_{α} radiation ($\lambda = 1.54056$ Å), operating at 40 kV and 40 mA. The XRD data were collected in the range of 10 °-60 ° in 2 θ by a step-scan mode with a step size of 0.02.

Photoluminescence spectra were measured at room temperature by a fluorescent spectrophotometer (F-4500, Hitachi Ltd., Tokyo, Japan) with a 200 W Xe-lamp as an excitation source. Emission spectra were corrected for the spectral response of a monochromater and Hamamatsu R928P photomultiplier tube by a light diffuser and tungsten lamp (Noma, 10 V, 4 A). Excitation spectra were also corrected for the spectral distribution of xenon lamp intensity by measuring Rhodamine-B as a reference. The quantum efficiency was determined on a Hamamatsu MPCD-7000 multichannel photo detector with a 200 W Xe-lamp as an excitation source.

The powder morphology was investigated by field-emission scanning electron microscopy (FESEM, JEOL-840A, Tokyo, Japan). The particle size distribution was recorded on the Microtrac particle size analyzer (CILAS 1064, Wisconsin, USA).

4. Conclusions

In order to enhance the photoluminescence properties of $SrSi_2O_2N_2:Eu^{2+}$ produced by a conventional solid state reaction, a variety of fluxes were used and their effects on photoluminescence were investigated. It was found that the flux material played a key role in synthesizing the $SrSi_2O_2N_2:Eu^{2+}$ phosphor particles via the solid state reaction. The particle size, particle morphology and photoluminescence intensity were largely dependent on the type of the flux material used and its addition amount. The melting point of the flux materials relative to the synthesizing temperature of the reaction was found to be an important consideration for selecting an appropriate flux. The chloride-based flux was found to work well for the formation of the $SrSi_2O_2N_2:Eu^{2+}$ phase. Among the chloride-based flux, the sample added with $SrCl_2$ had a narrow particle distribution and clean surface. The emission intensity and external quantum efficiency of the $SrSi_2O_2N_2:Eu^{2+}$ phosphor added with $SrCl_2$ was enhanced by 68% and 22%, respectively, compared with those obtained from the sample without any flux.

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Conflict of Interest

The authors declare no conflict of interest.

References

- Chiu, C.H.; Liu, C.H.; Huang, S.B.; Chen, T.M. Synthesis and luminescence properties of intensely red-emitting M₅Eu(WO₄)_{4-x}(MoO₄)_x (M = Li, Na, K) phosphors. *J. Electrochem. Soc.* 2008, *155*, J71–J78.
- 2. Li, Y.Q.; Delsing, A.C.A.; de With, G.; Hintzen, H.T. Luminescence properties of Eu^{2+} -activated alkaline-earth silicon-oxynitride $MSi_2O_{2-delta} N_{2+2/3 \ delta}$ (M = Ca, Sr, Ba): A promising class of novel LED conversion phosphors. *Chem. Mater.* **2005**, *17*, 3242–3248.
- 3. Xie, R.-J.; Hirosaki, N.; Sakuma, K.; Yamamoto, Y.; Mitomo, M. Eu²⁺-doped Ca-alpha-SiAlON: A yellow phosphor for white light-emitting diodes. *Appl. Phys. Lett.* **2004**, *84*, 5404–5406.
- 4. Wang, Z.L.; Liang, H.B.; Wang, J.; Gong, M.L.; Su, Q. Red-light-emitting diodes fabricated by near-ultraviolet InGaN chips with molybdate phosphors. *Appl. Phys. Lett.* **2006**, *89*, 071921:1–071921:3.
- 5. Xie, R.-J.; Hirosaki, N.; Mitomo, M.; Yamamoto, Y.; Suehiro, T.; Sakuma, K. Optical properties of Eu²⁺ in alpha-SiAION. *J. Phys. Chem. B* **2004**, *108*, 12027–12031.
- Kim, J.S.; Jeon, P.E.; Choi, J.C.; Park, H.L. Emission color variation of M₂SiO₄:Eu²⁺ (M = Ba, Sr, Ca) phosphors for light-emitting diode. *Solid State Commun.* 2005, *133*, 187–190.
- Zeng, Q.H.; He, P.; Pang, M.; Liang, H.B., Gong, M.L.; Su, Q. Sr₉R_{2-x}Eu_xW₄O₂₄ (R = Gd and Y) red phosphor for near-UV and blue InGaN-based white LEDs. *Solid State Commun.* 2009, *149*, 880–883.

- 8. Kim, K.N.; Kim, J.M.; Choi, K.J.; Park, J.K.; Kim, C.H. Synthesis, characterization, and luminescent properties of CaS:Eu phosphor. *J. Am. Ceram. Soc.* **2006**, *89*, 3413–3416.
- 9. Zhang, X.M.; Choi, N.; Park, K.; Kim, J. Orange emissive Sr₃Al₂O₅Cl₂:Eu²⁺ phosphor for warm-white light-emitting diodes. *Solid State Commun.* **2009**, *149*, 1017–1020.
- Kim, T.G.; Kim, Y.S.; Im, S.J. Energy Transfer and Brightness Saturation in (Sr,Ca)₂P₂O₇:Eu²⁺, Mn²⁺ Phosphor for UV-LED Lighting. *J. Electrochem. Soc.* **2009**, *156*, J203–J207.
- 11. Su, Y.K.; Peng, Y.M.; Yang, R.Y.; Chen, J.L. Effects of NaCl flux on microstructure and luminescent characteristics of KSrPO₄:Eu²⁺ phosphors. *Opt. Mater.* **2012**, *34*, 1598–1602.
- Teng, X.M.; Zhuang, W.D.; Hu, Y.S.; Zhao, C.L.; He, H.Q.; Huang, X.W. Effect of flux on the properties of CaAl₂O₄:Eu²⁺, Nd³⁺ long afterglow phosphor. *J. Alloys Compd.* 2008, 458, 446–449.
- 13. Lee, H.J.; Kim, K.P.; Hong, G.Y.; Yoo, J.S. The effect of flux materials on the physical and optical properties of Eu³⁺-activated yttrium oxide phosphors. *J. Lumin.* **2010**, *130*, 941–946.
- 14. Kang, Y.C.; Roh, H.S.; Park, S.B.; Park, H.D. Use of LiCl flux in the preparation of Y₂O₃:Eu phosphor particles by spray pyrolysis. *J. Eur. Ceram. Soc.* **2002**, *22*, 1661–1665.
- 15. Pan, Y.X.; Wu, M.M.; Su, Q. Tailored photoluminescence of YAG:Ce phosphor through various methods. *J. Phys. Chem. Solids* **2004**, *65*, 845–850.
- Conet, R.L.; Hansen, P.C.; Leask, M.J.M.; Wanklyn, B.M. Optical fluorescence excitation spectra of flux-grown stoichiometric europium vanadate crystals. J. Phys. Condens. Matter 1993, 5, 573–588.
- 17. Chen, Y.B.; Gong, M.L.; Cheah, K.W. Effects of fluxes on the synthesis of Ca₃Sc₂Si₃O₁₂:Ce³⁺ green phosphors for white light-emitting diodes. *Mater. Sci. Eng. B* **2010**, *166*, 24–27.
- 18. Lee, G.H.; Yoon, C.L.; Kang, S.H. Role of flux in the production process of red phosphors for white LEDs. J. Mater. Sci. 2008, 43, 6109–6115.
- Cho, Y.H.; Chalapathy, R.B.V.; Park, D.H.; Ahna, B.T. Low Temperature synthesis of Eu-Doped cubic phase BaAl₂S₄ blue phosphor using H₃BO₃ or B₂O₃ flux. *J. Electrochem. Soc.* 2010, 157, J45–J49.
- 20. Zhu, W.H.; Wang, P.L.; Sun, W.Y.; Yan, D.S. Phase-relationships in the Sr–Si–O–N system. *J. Mater. Sci.* **1994**, *13*, 560–562.

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